

# SANYO Semiconductors DATA SHEET

# $\textbf{LA73060V} \overset{\text{Monolithic Linear IC}}{---} \text{Wideband 75}\Omega \text{ Video Driver}$

#### Overview

This LA73060V is a wideband 75 $\Omega$  Video Driver IC. The LA73060V is ideal for use the video output driver such as TV-monitor and DVD-player equipment.

#### **Functions**

- 6channel output.
- 6MHz or 30MHz low pass filter.
- 6dB amplifier.
- Output mute.

- Y/C\_MIX.
- Standby mode.

#### **Specifications**

**Maximum Ratings** at  $Ta = 25^{\circ}C$ 

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		7.0	V
Allowable power dissipation	Pd max	Ta ≤ 75°C *	780	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +150	°C

<sup>\*</sup> When mounted on a 114.3×76.1×1.6mm³ glass epoxy board.

#### **Recommended Operating Conditions** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommending operation voltage	V <sub>CC</sub>		5.0	V
Operating voltage range	V <sub>CC</sub> op		4.75 to 5.25	V
Input pin voltage application range	v <sub>IN</sub>		-0.3 to V <sub>CC</sub> op + 0.3	V

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# **Electrical Characteristics** at Ta = 25°C, $V_{CC} = 5V$

Parameter	Symbol	SIG		Freq.	IN	OUT	Conditions		Ratings		Unit
Farameter	Symbol	310	[Vp-p]	[Hz]	point	point	Conditions	min	typ	max	Unit
Current dissipation 1	I <sub>CC</sub> 1						No signal.	69.0	87.0	105.0	mA
Current dissipation 2	I <sub>CC</sub> 2						Standby mode,No signal.	0.3	0.4	0.5	mA
Reguratur voltage	REG3V					T27		2.8	3.0	3.2	V
Voltage gain 1	V <sub>G</sub> 1	1	0.3	100k	T4A	T1	Output gain.	5.5	6.0	6.5	dB
	G				T6A	T35					
					T14A	T22					
					T12A	T30					
					T14A	T28					
					T16A	T26					
Voltage gain 2	V <sub>G</sub> 2	3	0.3	100k	T8A	T32	Output gain.	5.5	6.0	6.5	dB
					T12A	T24					
					T16A	T19					
Frequency	V <sub>F</sub> 1 (SD)	1	0.3	6M	T4A	T1	6MHz LPF is selected.	-3	0.0	3	dB
characteristics 1					T6A	T35	f = 6MHz / 100kHz.				
$(CV,Y,P_y,R,G,B)$					T14A	T22					
					T12A	T30					
					T14A	T28					
<b>-</b>	)/ 0 (OD)		0.0	014	T16A	T26	OMIL I DE la calculata	-	0.0	0	ı.
Frequency	V <sub>F</sub> 2 (SD)	3	0.3	6M	T8A	T32	6MHz LPF is selected.	-3	0.0	3	dB
characteristics 2					T12A T16A	T24 T19	f = 6MHz / 100kHz.				
(C,P <sub>r</sub> ,P <sub>b</sub> )		<u> </u>									
Frequency	V <sub>F</sub> 3 (SD)	1	0.3	27M	T4A	T1	6MHz LPF is selected.		-40	-35	dB
characteristics 3					T6A	T35	f = 27MHz / 100kHz.				
$(CV,Y,P_y,R,G,B)$					T14A T12A	T22					
					T14A	T30 T28					
					T16A	T26					
Frequency	V <sub>F</sub> 4 (SD)	3	0.3	27M	T8A	T32	6MHz LPF is selected.		-40	-35	dB
characteristics 4	VF+ (OD)		0.0	27 IVI	T12A	T24	f = 27MHz / 100kHz.		40	00	uВ
$(C,P_r,P_b)$					T16A	T19	. 27111127 100111121				
Frequency	V <sub>F</sub> 5 (HD)	1	0.3	20M	T14A	T22	30MHz LPF is selected.	-1	0.0	1	dB
characteristics 5	VF3 (11D)	'	0.3	ZUIVI	T12A	T30	f =20MHz / 100kHz.	-1	0.0	'	uБ
ondraotonotios o					T14A	T28	1 -201411 12 / 100KI 12.				
					T16A	T26					
Frequency	V <sub>F</sub> 6 (HD)	3	0.3	20M	T12A	T24	30MHz LPF is selected.	-1	0.0	1	dB
characteristics 6	1 - ( )				T16A	T19	f = 20MHz / 100kHz.				
Frequency	V <sub>F</sub> 7 (HD)	1	0.3	30M	T14A	T22	30MHz LPF is selected.	-5	-2.5	0	dB
characteristics 7					T12A	T30	f = 30MHz / 100kHz.				
					T14A	T28					
					T16A	T26					
Frequency	V <sub>F</sub> 8 (HD)	3	0.3	30M	T12A	T24	30MHz LPF is selected.	-5	-2.5	0	dB
characteristics 8					T16A	T19	f = 30MHz / 100kHz.				
Frequency	V <sub>F</sub> 9 (HD)	1	0.3	75M	T14A	T22	30MHz LPF is selected.	1 7	-40	-35	dB
characteristics 9					T12A	T30	f = 75MHz / 100kHz.				
					T14A	T28					
					T16A	T26					
Frequency	V <sub>F</sub> 10 (HD)	3	0.3	75M	T12A	T24	30MHz LPF is selected.		-40	-35	dB
characteristics 10					T16A	T19	f = 75MHz / 100kHz.				

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Parameter	Symbol	SIG	Level	Freq.	IN	OUT	Conditions		Ratings		Unit
Parameter	Symbol	SIG	[Vp-p]	[Hz]	point	point	min	typ	max	Unit	
2nd order distortion 1	Dst1 (SD)	1	0.7	4M	T4A	T1A			-40	-35	dE
(SD)					T6A	T35A					
					T14A	T22A					
					T12A	T30A					
					T14A	T28A					
					T16A	T26A					
2nd order distortion 2	Dst2 (SD)	3	0.7	4M	T8A	T32A			-40	-35	dE
(SD)					T12A	T24A					
					T16A	T19A					
2nd order distortion 3	Dst3 (HD)	1	0.7	10M	T14A	T22A			-40	-35	dE
(HD)					T12A	T30A					
					T14A	T28A					
					T16A	T26A					
2nd order distortion 4	Dst4 (HD)	3	0.7	10M	T8A	T32A			-40	-35	dE
(HD)	,		-	-	T12A	T24A					
,					T16A	T19A					
Clipping output level 1	V <sub>O</sub> max1	3	2	100k	T4A	T1	Output level for clipping.	2.2	2.4		Vp-
onpping output love.	- U.I.axi		_		T6A	T35					٠,٢
					T14A	T22					
					T12A	T30					
					T14A	T28					
					T16A	T26					
Clipping output level 2	V <sub>O</sub> max2	3	2	100k	T8A	T32	Output level for clipping.	2.2	2.4		Vp-
Clipping output level 2	VOIIIaxz	3		TOOK	T12A	T24	Output level for clipping.	2.2	2.4		v p-
					T16A	T19					
Amount of muto	V <sub>M</sub> 1	1	0.3	4M	T4A	T1			-60	-50	dE
Amount of mute	νMι	'	0.3	4IVI	T6A	T35			-60	-50	ÜE.
attenuation 1					T14A	T22					
					T12A	T30					
					T14A	T28					
		_			T16A	T26					
Amount of mute	V <sub>M</sub> 2	3	0.3	4M	T8A	T32			-60	-50	dE
attenuation 2					T12A	T24					
					T16A	T19					
Crosstalk between	V <sub>CT</sub> 1	1	0.3	4M	T4A				-60	-50	dE
channels 1					T6A						
					T14A						
					T12A						
					T14A						
					T16A						
Crosstalk between	V <sub>CT</sub> 2	3	0.3	4M	T8A				-60	-50	dE
channels 2					T12A						
onamois z		l			T16A						

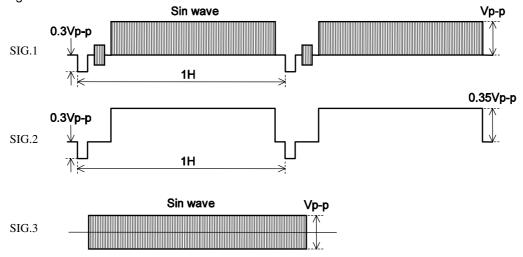
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_			Level	Freq.	IN	OUT			Ratings		
Parameter	Symbol	SIG	[Vp-p]	[Hz]	point	t point	Conditions	min	typ	max	Unit
Video S/N 1	V <sub>S/N</sub> 1 (SD)	2	0.65		T4A	T1A	V <sub>IN</sub> = Video (50% White),		-70	-60	dB
(SD)					T6A	T35A	The band is between 100kHz				
					T14A	T22A	and 4.2MHz				
					T12A	T30A					
					T14A	T28A					
					T16A	T26A					
Video S/N 2	V <sub>S/N</sub> 2 (HD)	2	0.65		T14A	T22A	V <sub>IN</sub> = Video (50% White),		-60	-50	dB
(HD)					T12A	T30A	The band is between 100kHz				
					T14A	T28A	and 30MHz				
					T16A	T26A					
Group delay 1	GD1 (SD)	1	0.3	6M	T4A	T1	Input / Output delay time.		20	30	ns
(SD)					T6A	T35	f=6MHz/100kHz				
					T14A	T22					
					T12A	T30					
					T14A	T28					
					T16A	T26					
Group delay 2	GD2 (SD)	3	0.3	6M	T8A	T32	Input / Output delay time.		20	30	ns
(SD)					T12A	T24	f=6MHz/100kHz				
					T16A	T19					
Group delay 3	GD3 (HD)	1	0.3	30M	T14A	T22	Input / Output delay time.		10	20	ns
(HD)					T12A	T30	f=30MHz/100kHz				
					T14A	T28					
					T16A	T26					
Group delay 4	GD4 (HD)	3	0.3	30M	T12A	T24	Input / Output delay time.	_	10	20	ns
(HD)					T16A	T19	f=30MHz/100kHz				



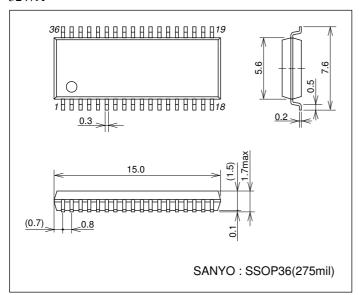


# **Truth Table**

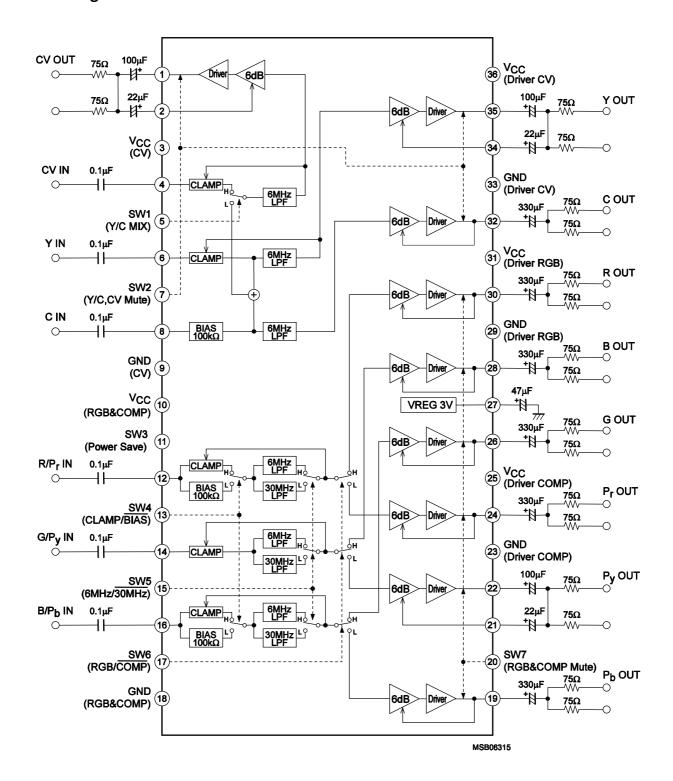
SW No.	Pin No.	Function	H (2.3V to V <sub>CC</sub> )	L (0 to 0.7V)	
SW1	5	Y/C MIX	OFF	ON	
SW2	7	CV Mute control	OFF	ON	
SW3	11	Power save control OFF		ON	
SW4	13	Input control	CLAMP ON(RGB Mode)	BIAS ON(Component Mode)	
SW5	15	Filter control	6MHz LPF ON(RGB Mode)	30MHz LPF ON(Component Mode)	
SW6	17	Output control	RGB ON(RGB Mode)	Component ON(Component Mode)	
SW7	20	RGB&Component Mute control	OFF	ON	

## **Package Dimensions**

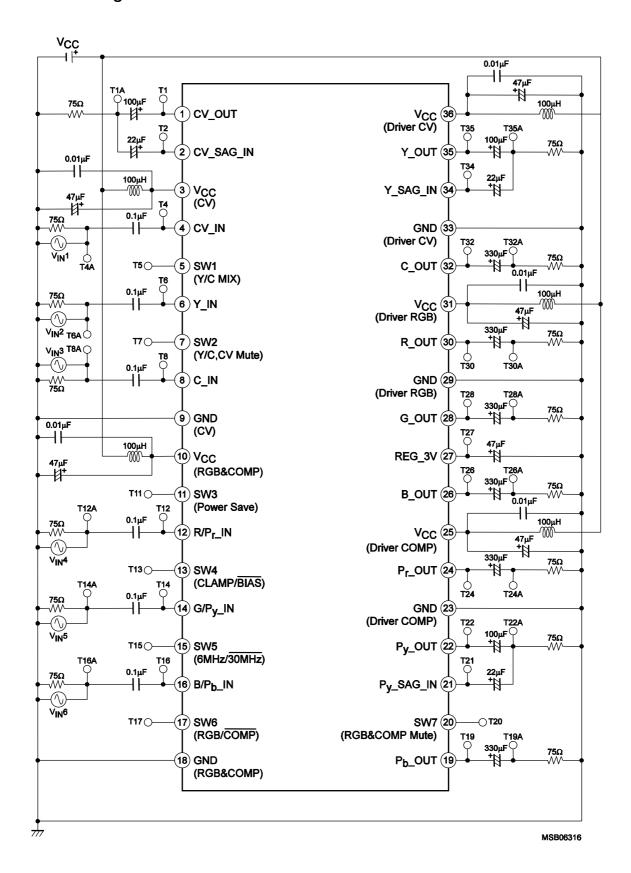
unit : mm 3247A



#### **Block Diagram**



#### **Test Circuit Diagram**



## **LA73060V**

## **Pin Functions**

Pin No.	Pin Name	Signal Wave Form	Equivalent Circuit
1	CV_OUT	2.0Vp-p	See
35	Y_OUT	2.0Vp-p 1.2V	
2	CV_SAG_IN	2.0Vp-p	1.1kΩ 1.25kΩ 400Ω
21 34	P <sub>y</sub> _SAG_IN Y_SAG_IN	2.0Vp-p	1.1kΩ 1.25kΩ 400Ω 400Ω
4	CV_IN	1.0Vp-p 1.75V	↑
6	Y_IN	Y_IN,Py_IN  1.0Vp-p  1.75V	\$\$\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
14	G/P <sub>y</sub> _IN	0.7Vp-p 1.75V	M
5 7 11 13 15 17 20	SW1 SW2 SW3 SW4 SW5 SW6 SW7	*See the Truth Table.	100kg 10kg
3 10 25 31 36	V <sub>CC</sub> (CV)  V <sub>CC</sub> (RGB&COMP)  V <sub>CC</sub> (Driver COMP)  V <sub>CC</sub> (Driver RGB)  V <sub>CC</sub> (Driver CV)		

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Pin No.	Pin Name	Signal Wave Form	Equivalent Circuit
8	C_IN	2.3V	180, Aug. 180, A
12 16	R/P <sub>r</sub> _IN B/P <sub>b</sub> _IN	0.7Vp-p	Clamp OFF OFF OFF OFF OFF OFF OFF OFF OFF OF
26	B_OUT	<del> </del>	
28 30	G_OUT R_OUT	1.4Vp-p	\$g
19 24	P <sub>b</sub> _OUT P <sub>r</sub> _OUT	2.3V 1.4Vp-p	1.3kΩ 1.5kΩ
32	C_OUT	2.3V ————————————————————————————————————	
9 18 23 29 33	GND (CV) GND (RGB&COMP) GND (Driver COMP) GND (Driver RGB) GND (Driver CV)		
27	REG3V	DC:3.0V	30kg 32kg 32kg 32kg 32kg 32kg 32kg 32kg 32

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